



STG3157

Low voltage low on-resistance SPDT switch with break-before-make feature

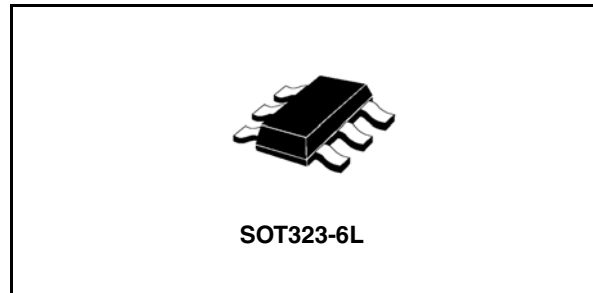
Features

- High speed:
 - $t_{PD} = 0.3 \text{ ns}$ (max) at $V_{CC} = 4.5 \text{ V}$
 - $t_{PD} = 0.8 \text{ ns}$ (max) at $V_{CC} = 3.0 \text{ V}$
 - $t_{PD} = 1.2 \text{ ns}$ (max) at $V_{CC} = 2.3 \text{ V}$
- Ultra low power dissipation:
 - $I_{CC} = 1 \mu\text{A}$ (max) at $T_A = 85^\circ\text{C}$
- Low on-resistance; at $V_{IN} = 0 \text{ V}$:
 - $R_{ON} = 7 \Omega$ (max $T_A = 85^\circ\text{C}$) at $V_{CC} = 4.5 \text{ V}$
 - $R_{ON} = 9 \Omega$ (max $T_A = 85^\circ\text{C}$) at $V_{CC} = 3.0 \text{ V}$
- Wide operating voltage range:
 - V_{CC} (OPR) = 1.65 V to 5.5 V single supply
- TTL threshold ON control input at $V_{CC} = 2.7$ to 3.6 V
- Pin and function compatible with 74 series 3157
- Latch-up performance exceeds 150 mA (JESD 17)

Description

The STG3157 is a high-speed CMOS analog SPDT (single-pole double-throw) switch or 2:1 multiplexer/demultiplexer bus switch manufactured using silicon gate $C^2\text{MOS}$ technology. It is designed to operate from a 1.65 V to 5.5 V supply, making the device ideal for portable applications.

The STG3157 features very low on-resistance ($< 9 \Omega$) at $V_{CC} = 3.0 \text{ V}$. The IN input is provided to control the SPDT switch, and is compatible with standard CMOS output. Switch S1 is ON



(connected to common port D) when the IN input is held high, and OFF (a high impedance state exists between the two ports) when IN is held low. Switch S2 is ON (connected to common port D) when the IN input is held low and OFF (a high impedance state exists between the two ports) when IN is held high.

Additional key features are fast switching speed, break-before-make delay time, and very low power consumption. All inputs and outputs are equipped with protection circuits to protect against static discharge, giving them immunity from ESD and transient excess voltage.

Table 1. Device summary

Order code	Package	Packing
STG3157CTR	SOT323-6L	Tape and reel

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1 Pin connections and functions

Figure 1. Pin connections and IEC logic symbols

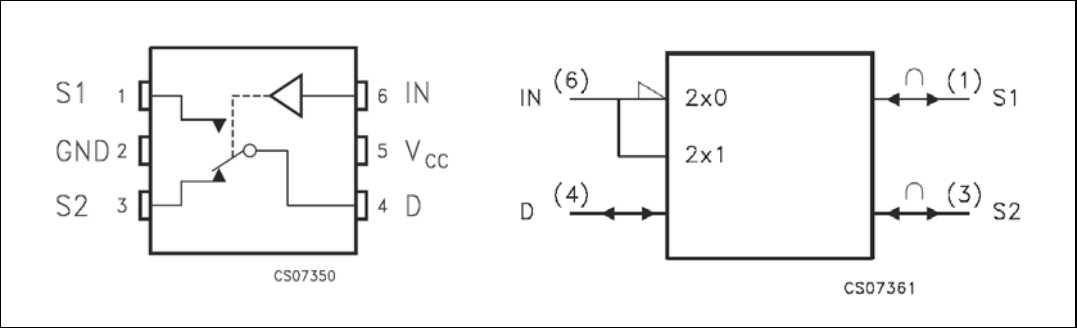


Table 2. Truth table

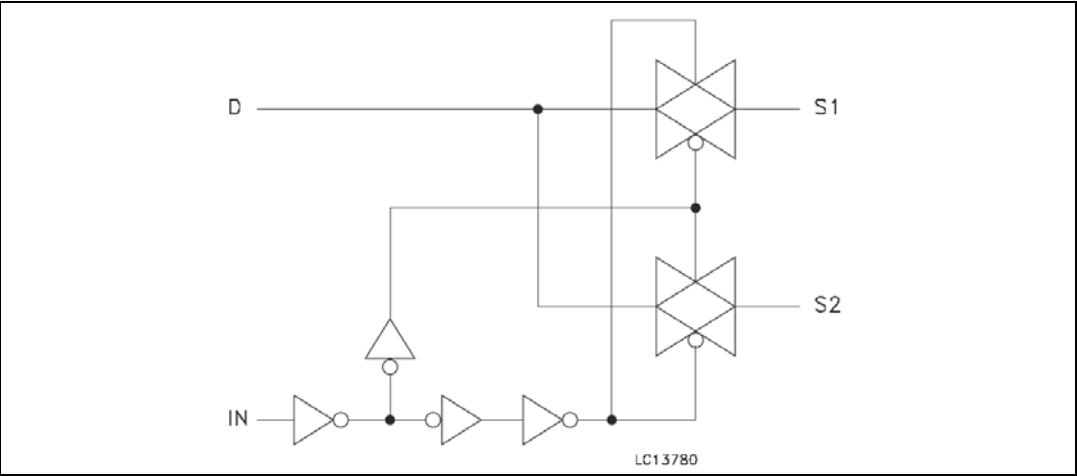
IN	Switch S1	Switch S2
H	ON	OFF ⁽¹⁾
L	OFF ⁽¹⁾	ON

1. High impedance

Table 3. Pin descriptions

Pin N°	Symbol	Name and function
1, 3	S1, S2	Independent channels
4	D	Common channels
6	IN	Control
5	V _{CC}	Positive supply voltage
2	GND	Ground (0 V)

Figure 2. Input equivalent circuit



2 Electrical ratings

Stressing the device above the ratings listed in the “Absolute maximum ratings” table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	-0.5 to +7.0	V
V_I	DC input voltage	-0.5 to $V_{CC} + 0.5$	V
V_{IC}	DC control input voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC output voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IKC}	DC input diode current on control pin ($V_{IN} < 0V$)	± 50	mA
I_{IK}	DC input diode current ($V_{IN} < 0V$)	± 50	mA
I_{OK}	DC output diode current	± 20	mA
I_O	DC output current	+128	mA
I_{CC} or I_{GND}	DC V_{CC} or ground current	± 100	mA
T_{stg}	Storage temperature	-65 to 150	°C
T_L	Lead temperature (10 s)	300	°C

Table 5. Recommended operating conditions

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage ⁽¹⁾	1.65 to 4.5	V
V_I	Input voltage	0 to V_{CC}	V
V_{IC}	Control input voltage	0 to 5.5	V
V_O	Output voltage	0 to V_{CC}	V
T_{op}	Operating temperature	-55 to 125	°C
dt/dv	Input rise and fall time control input	$V_{CC} = 1.65V$ to $2.7V$	ns/V
		$V_{CC} = 3.0$ to $4.5V$	

1. Truth table guaranteed: 1.2 V to 6.0 V

3 Electrical characteristics

3.1 DC Electrical characteristics

Table 6. DC specifications

Symbol	Parameter	Test conditions		Value							Unit
		Vcc (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V _{IH}	High level input voltage	1.65-1.95		0.75V _{CC}			0.75V _{CC}		0.75V _{CC}		V
		2.3-2.5		0.7V _{CC}			0.7V _{CC}		0.7V _{CC}		
		2.7-3.6		2			2		2		
V _{IL}	Low level input voltage	1.65-1.95				0.25V _{CC}		0.25V _{CC}		0.25V _{CC}	V
		2.3-2.5				0.3V _{CC}		0.3V _{CC}		0.3V _{CC}	
		2.7-3.6				0.8		0.8		0.8	
R _{ON}	Switch on-resistance	4.5	V _S = 0V I _S = 30mA		4.4	7		7		9	Ω
			V _S = 2.4V I _S = 30mA		4.9	12		12		14.5	
			V _S = 4.5V I _S = 30mA		6.1	15		15		18	
		3.0	V _S = 0V I _S = 100mA		5.2	9		9		11	
			V _S = 3V I _S = 24mA		7.8	20		20		24	
		2.3	V _S = 0V I _S = 8mA		6.5	12		12		14.5	
			V _S = 2.3V I _S = 8mA		9.6	30		30		36	
		1.65	V _S = 0V I _S = 4mA		9.0	20		20		24	
			V _S = 1.65V I _S = 4mA		14	50		50		60	
ΔR _{ON}	On-resistance match between channels	4.5	V _S = 3.15V I _S = 30mA		0.10						Ω
		3.0	V _S = 2.1V I _S = 24mA		0.10						
		2.3	V _S = 1.6V I _S = 8mA		0.20						
		1.65	V _S = 1.15V I _S = 4mA		0.35						

Table 6. DC specifications (continued)

Symbol	Parameter	Test conditions		Value							Unit
		Vcc (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
R _{FLAT}	On-resistance flatness	5.0	V _S = 0V to V _{CC} I _S = 30mA		3						Ω
		3.3	V _S = 0V to V _{CC} I _S = 24mA		6						
		2.5	V _S = 0V to V _{CC} I _S = 8mA		14						
		1.8	V _S = 0V to V _{CC} I _S = 4mA		80						
I _{OFF}	OFF state leakage current	1.65-195	V _S = 0 to V _{CC}		±0.05	±0.1		±1		±10	μA
I _{IN}	Input leakage current	0 - 5.5	V _{IN} = 0 to 5.5V		±0.05	±0.1		±1		±10	μA
I _{CC}	Quiescent supply current	1.65 - 4.3	V _{IN} = V _{CC} or GND			1		1		10	μA

3.2 AC Electrical characteristics

$C_L = 50 \text{ pF}$, $R_L = 500 \Omega$

Table 7. AC specification

Symbol	Parameter	Test conditions		Value						Unit	
		Vcc (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
t _{LH} , t _{HL}	Propagation delay	1.65-1.95	V _I = Open								ns
		2.3-2.7				1.2		1.2		1.8	
		3.0-3.3				0.8		0.8		1.2	
		4.5-5.5				0.3		0.3		0.5	
t _{PZH} , t _{PZL}	Output enable time (D to Sn)	1.65-1.95		7		15	7	20	7	27	ns
		2.3-2.7		3.5		11	3.5	14	3.5	17	
		3.0-3.3		2.5		7	2.5	7.6	2.5	9	
		4.5-5.5		1.7		5.2	1.7	5.7	1.7	7	
t _{PLZ} , t _{PHZ}	Output disable time (D to Sn)	1.65-1.95		3		10	3	13	3	16	ns
		2.3-2.7		2		7	2	7.5	2	9	
		3.0-3.3		1.5		5	1.5	5.3	1.5	6.5	
		4.5-5.5		1.7		3.5	1.7	3.8	1.7	5	
t _D	Break-before-make time delay	1.65-5.5		0.5			0.5		0.5		ns
Q	Charge injection	5			23						pC
		3.3			19						

3.3 Analog switch characteristics

$C_L = 5 \text{ pF}$, $R_L = 50 \Omega$, $T_A = 25^\circ\text{C}$

Table 8. Analog switch characteristics

Symbol	Parameter	Test conditions		Value						Unit	
		Vcc (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
OIRR	Off isolation	1.65-5.5	R _L = 50Ω f = 10MHz		-57						dB
Xtalk	Crosstalk	1.65-5.5	R _L = 50Ω f = 10MHz		-54						dB
BW	-3dB bandwidth	1.65-5.5	R _L = 50Ω		250						MHz
C _{IN}	Control pin input capacitance				5						pF
C _{Sn}	Sn port capacitance	5.0	f = 1MHz		13						
C _D	D port capacitance when switch is enabled	5.0	f = 1MHz		21						

4 Test circuits

Figure 3. On-resistance

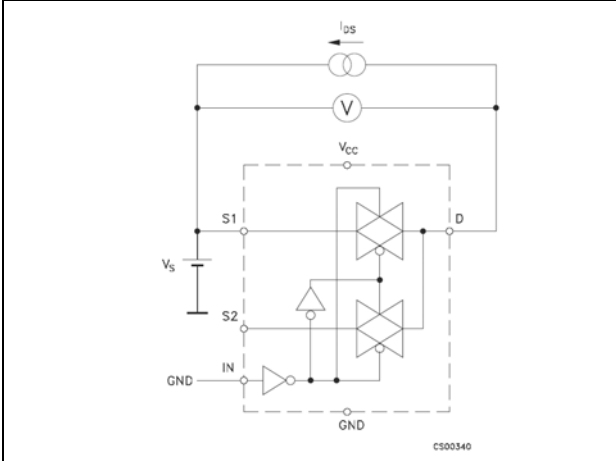


Figure 4. Bandwidth

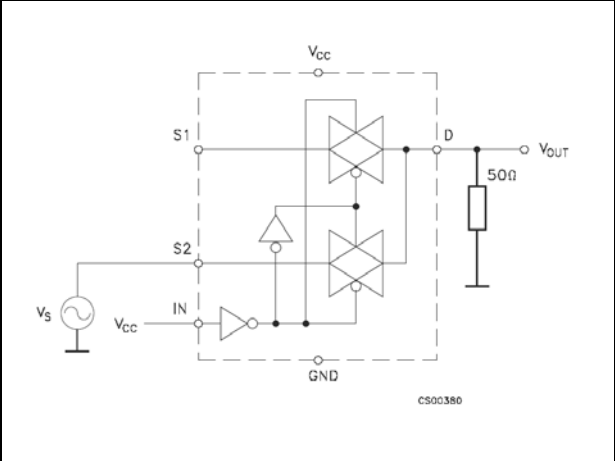


Figure 5. OFF leakage

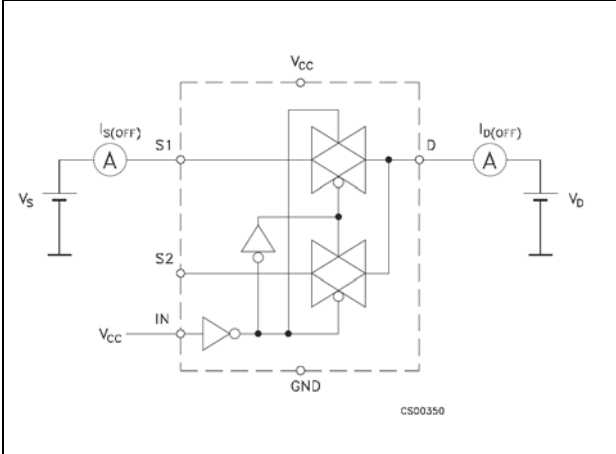


Figure 6. Channel-to-channel crosstalk

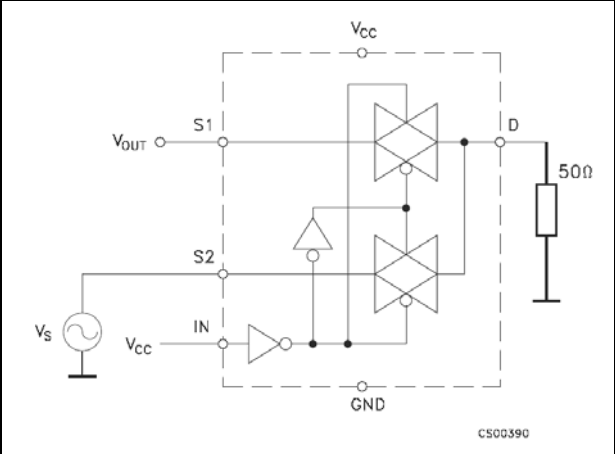


Figure 7. OFF isolation

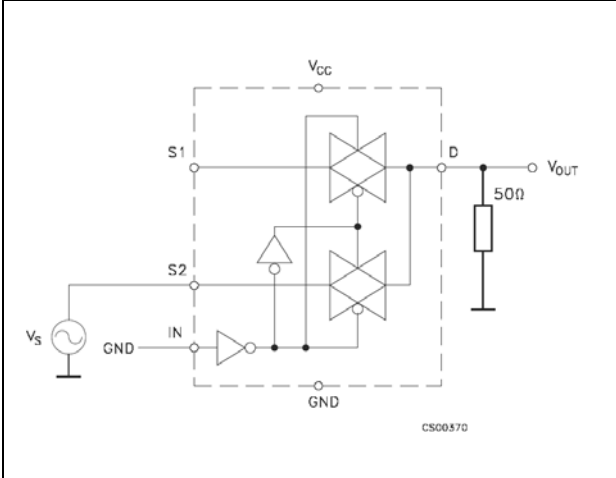


Figure 8. ON leakage

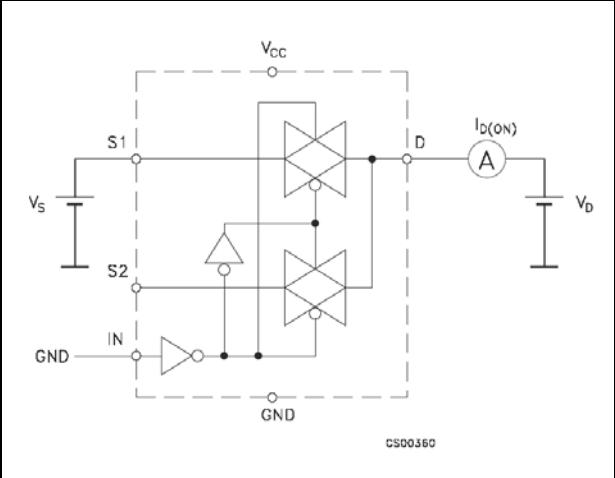


Figure 9. Test circuit

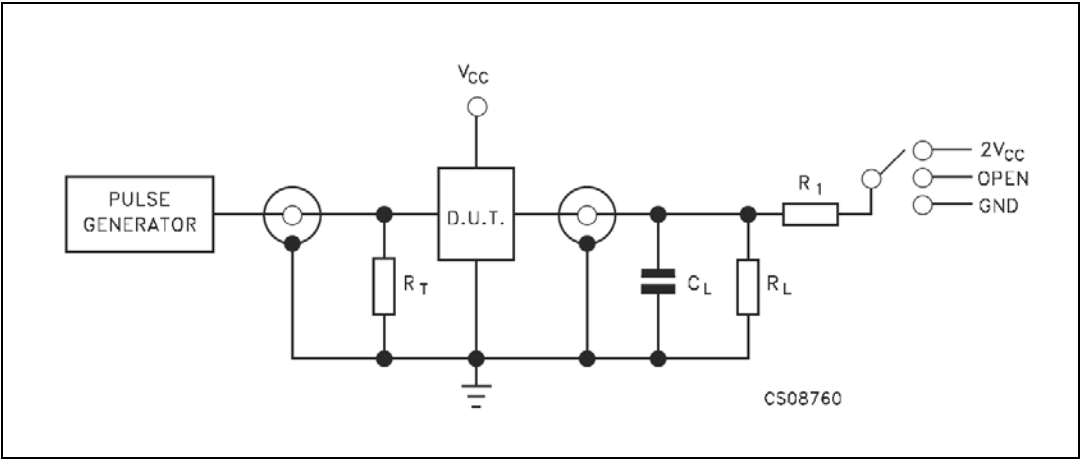


Table 9. Test circuit

Test	Switch
t_{PLH} , t_{PHL}	Open
t_{PZL} , t_{PLZ}	V_{CC}
t_{PZH} , t_{PHZ}	GND

Note:

- $C_L = 5/35$ pF or equivalent: (includes jig capacitance)
- $R_L = 50 \Omega$ or equivalent
- $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

Figure 10. Break-before-make time delay

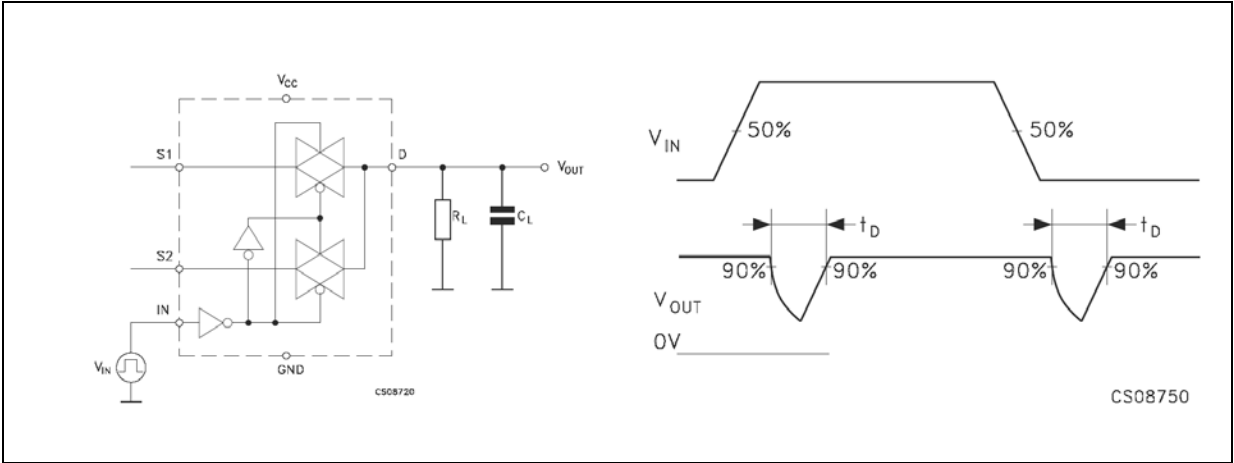
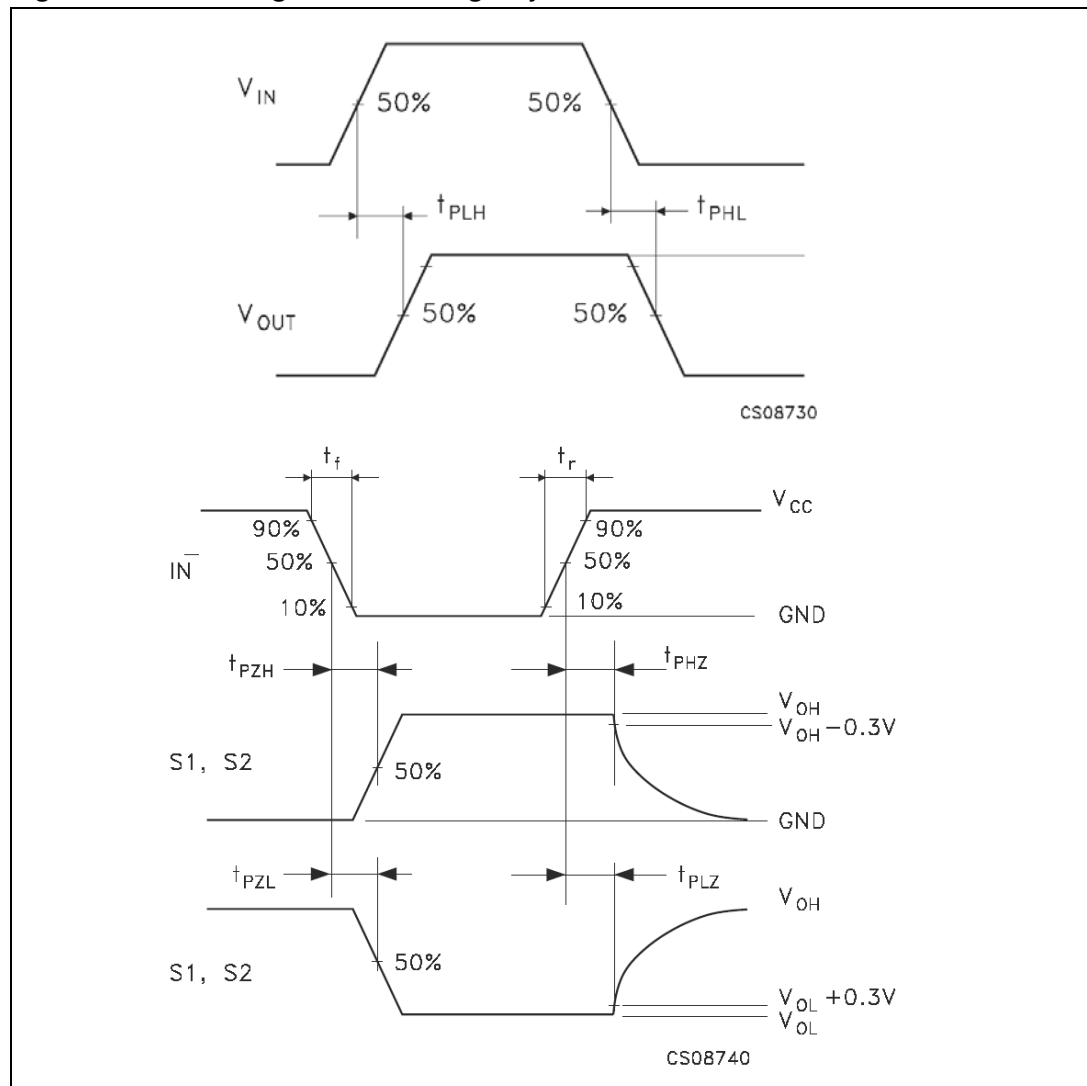
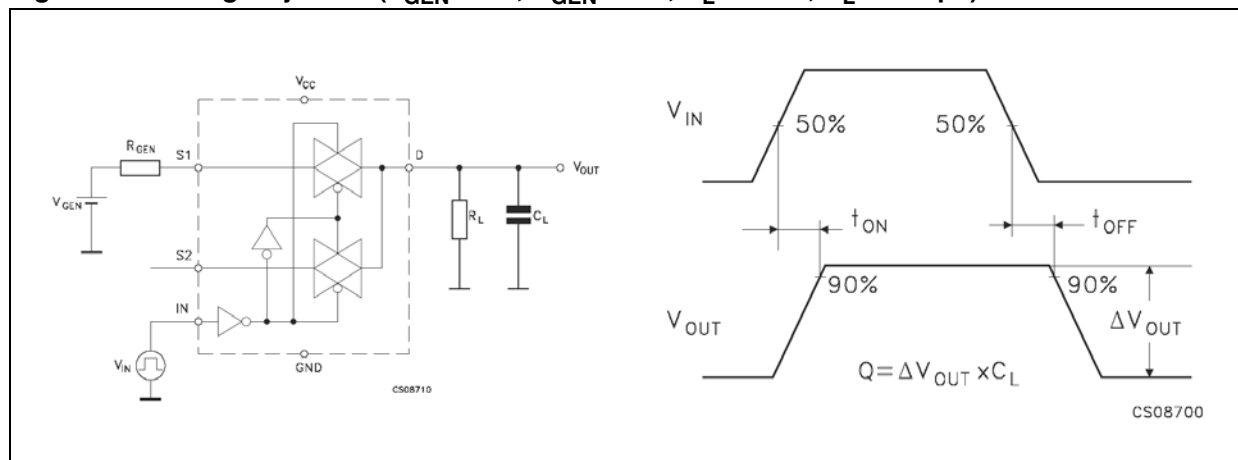


Figure 11. Switching time and charge injection

Figure 12. Charge injection ($V_{GEN} = 0\text{ V}$, $R_{GEN} = 0\ \Omega$, $R_L = 1\text{ M}\Omega$, $C_L = 100\text{ pF}$)

5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 10. SOT323-6L mechanical data

Dim.	mm.			inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.80		1.10	31.5		43.3
A1	0.00		0.10	0.0		3.9
A2	0.80		1.00	31.5		39.4
b	0.15		0.30	5.9		11.8
C	0.10		0.18	3.9		7.1
D	1.80		2.20	70.9		86.6
E	1.80		2.40	70.9		94.5
E1	1.15		1.35	45.3		53.1
e		0.65			25.6	
e1		1.3			51.2	
L	0.10		0.30	3.9		11.8

Figure 13. Package dimensions

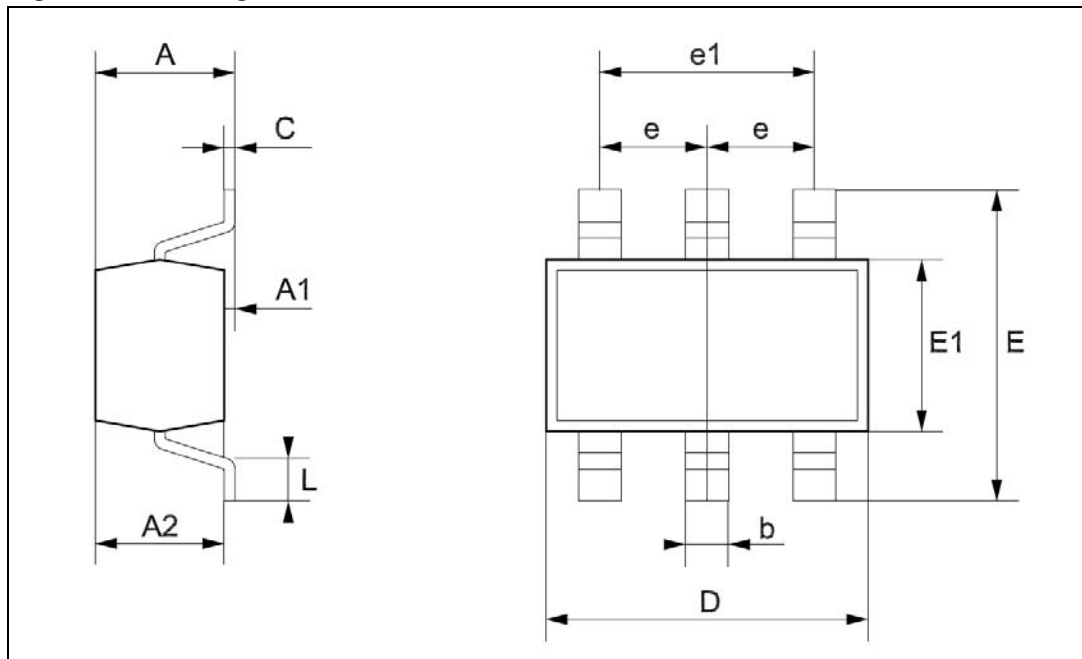


Table 11. SOT323-6L footprint recommendation

Dim.	mm.	inch
A	2.88	0.113
B	0.78	0.031
C	0.36	0.014
D	0.65	0.026
E	1.05	0.041
F	1.65	0.065

Figure 14. SOT323-6L footprint recommendation

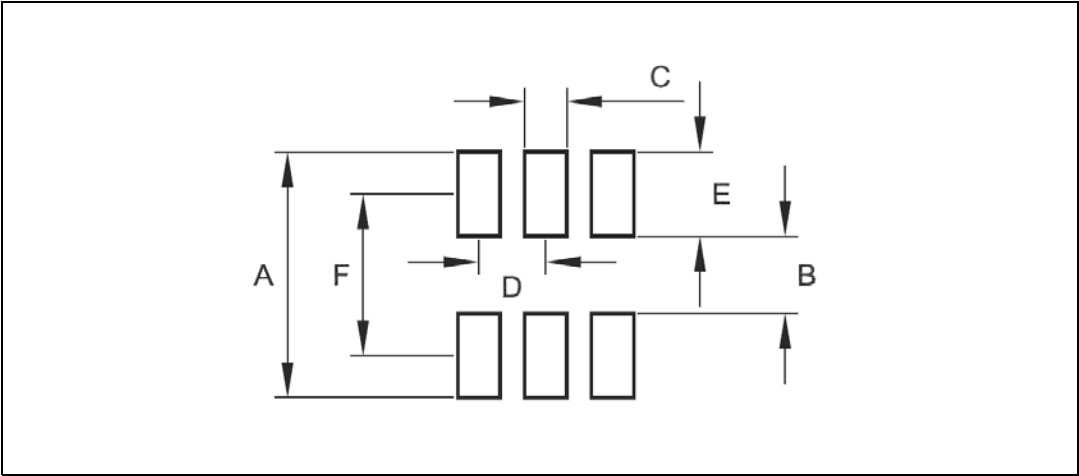


Table 12. SOT323-6L tape information

Dim	mm.	inch
D	$1.50 \pm 0.1/0$	$0.059 \pm 0.004/0$
E	1.75 ± 0.1	0.069 ± 0.004
Po	4.00 ± 0.1	0.157 ± 0.004
T max.	0.40	0.016
D1 min.	1	0.039
F	3.5 ± 0.05	0.138 ± 0.002
K max.	2.40	0.094
P2	2.00 ± 0.05	0.079 ± 0.002
R	25	0.984
W	8.00 ± 0.30	0.315 ± 0.012
P1	4.00	0.157
Ao, Bo, Ko	0.05 min to 0.50 max	0.002 min to 0.020 max

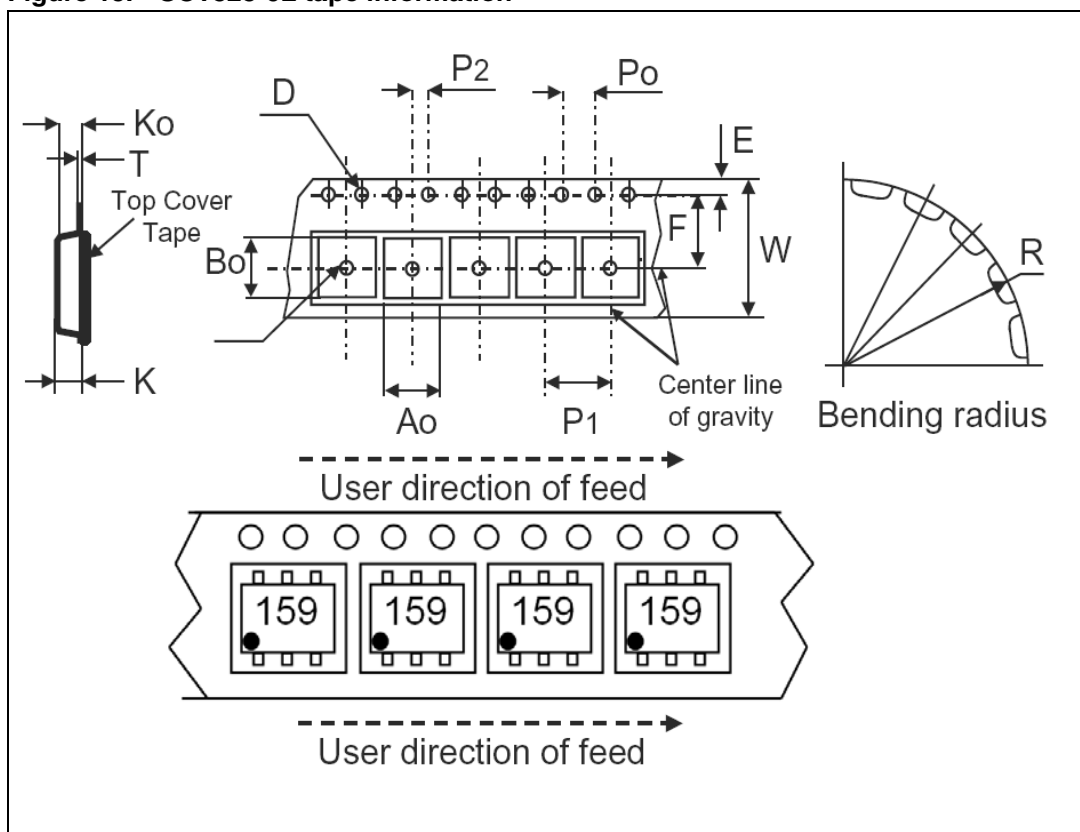
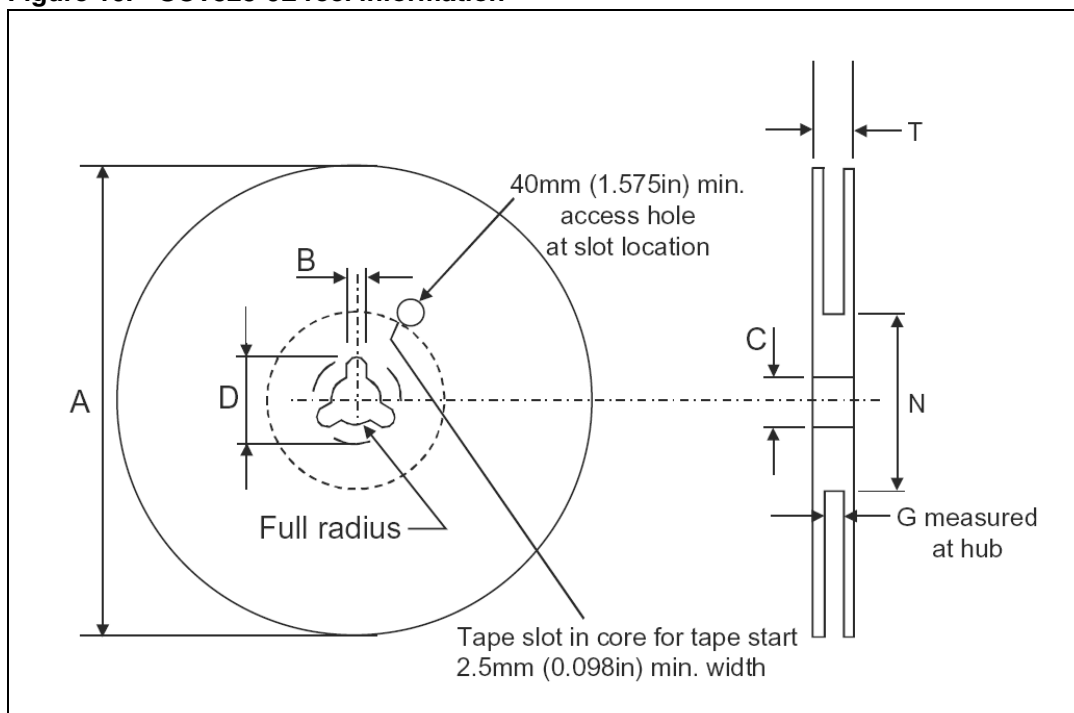
Figure 15. SOT323-6L tape information

Table 13. SOT323-6L reel information

Dim	mm.	inch
Tape size	8.0 ± 0.30	0.315 ± 0.012
A max.	180.0	7.086
B min.	1.5	0.059
C	13.0 ± 0.20	0.512 ± 0.008
D min.	20.2	0.795
N min.	60	2.362
G	$8.4 +2/-0$	$0.319 +0.079/-0$
T max.	14.4	0.567

Figure 16. SOT323-6L reel information

6 Revision history

Table 14. Document revision history

Date	Revision	Changes
02-Sep-2002	1	Initial release.
19-Apr-2010	2	Document reformatted. In the Features list on the coverpage, updated the “Latch-up performance exceeds” value from 300 mA to 150 mA. Minor text changes throughout the document. Replaced Order codes table on the coverpage with Table 1: Device summary . Added ECOPACK® statement in Section 5: Package information .

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